## Features:

- TO-72 hermetically sealed package
- 1 kVDC electrical isolation
- High current transfer ratio
- TX devices processed to MIL-PRF-19500



## Description:

Each device is a high reliability optically coupled isolator that consists of an infrared emitting diode and a NPN silicon phototransistor which are mounted in a hermetically sealed TO-72 package. The 3C91C and 3C92C have a 935 nm wavelength, whereas the 3N243, 3N244, 3N245 and $\mathbf{3 N} 262$ have an 880 nm wavelength. All devices have $0.50^{\prime \prime}(12.70 \mathrm{~mm})$ leads. Electrical characteristics vary.

TX devices are processed to OPTEK's military screening program patterned after MIL-PRF-19500.
Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.
Contact your local representative or OPTEK for more information.

## Applications:

- High-voltage isolation between input and output
- Electrical isolation in dirty environments
- Industrial equipment
- Medical equipment
- Office equipment

| Part <br> Number | LED <br> Peak <br> Wavelength | Sensor | Isolation Voltage $(, 000)$ | CTR <br> Min / Max | $\begin{gathered} \mathrm{I}_{\mathrm{F}}(\mathrm{~mA}) \\ \text { Typ / Max } \end{gathered}$ | $\begin{gathered} \hline \mathrm{V}_{\mathrm{CE}}(\mathrm{~V}) \\ \mathrm{Typ} / \\ \mathrm{Max} \end{gathered}$ | Lead Length |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 3C91C |  | Transistor | 1 |  |  |  | 0.50" |
| 3C92C (TX) | 35 |  |  | 0.3 / 2.0 | 10/50 | 10/50 |  |
| 3N243 | 880 nm |  |  | 0.15 / NA | $3 / 40$ | 10 / 30 |  |
| 3N244 |  |  |  | 0.3 / NA |  |  |  |
| 3N245 (TX) |  |  |  | 0.6 / NA |  |  |  |
| 3N262 |  |  |  | 1.0 / 5.0 | 1 / 40 | $5 / 30$ |  |



## Electrical Specifications

Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Operating Temperature Range | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| :--- | ---: |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Input to Output Isolation Voltage | $\pm 1 \mathrm{kVDC}{ }^{(1)}$ |
| Lead Soldering Temperature [1/16 inch $(1.6 \mathrm{~mm})$ from case for 5 seconds with soldering iron] | $260^{\circ} \mathrm{C}^{(2)}$ |

Input Diode

| Forward DC Current | 40 mA |
| :--- | :---: |
| Reverse Voltage | 2.0 V |
| Power Dissipation | $60 \mathrm{~mW}{ }^{(3)}$ |

Output Phototransistor

| Continuous Collector Current | 30 mA |
| :--- | ---: |
| Collector-Emitter Voltage | 30 V |
| Emitter-Collector Voltage | 5.0 V |
| Power Dissipation | $200 \mathrm{~mW}^{(4)}$ |

Notes:

1. Measured with input leads shorted together and output leads shorted together.
2. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
3. Derate linearly $2.0 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $25^{\circ} \mathrm{C}$.
4. Derate linearly $0.60 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $65^{\circ} \mathrm{C}$.


## Electrical Specifications

Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |

Input Diode

| $V_{F}$ | Forward Voltage 3C91C, 3C92C (TX) 3C91C, 3C92C (TX) 3N243, 3N244, 3N245 (TX) 3N243, 3N244, 3N245 (TX) 3N243, 3N244, 3N245 (TX) 3N262 3N262 3N262 | $\begin{gathered} - \\ 0.8 \\ 1.0 \\ 0.7 \\ 0.8 \\ 1.0 \\ 0.7 \end{gathered}$ |  | $\begin{aligned} & 1.2 \\ & 1.5 \\ & 1.3 \\ & 1.5 \\ & 1.2 \\ & 1.5 \\ & 1.7 \\ & 1.3 \end{aligned}$ | V | $\begin{aligned} & I_{F}=2 \mathrm{~mA} \\ & I_{F}=50 \mathrm{~mA} \\ & I_{F}=10 \mathrm{~mA} \\ & I_{F}=10 \mathrm{~mA}, T_{A}=-55^{\circ} \mathrm{C} \\ & I_{F}=10 \mathrm{~mA}, T_{A}=-100^{\circ} \mathrm{C} \\ & I_{F}=10 \mathrm{~mA} \\ & I_{F}=10 \mathrm{~mA}, T_{A}=-55^{\circ} \mathrm{C} \\ & I_{F}=10 \mathrm{~mA}, T_{A}=-100^{\circ} \mathrm{C} \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {R }}$ | $\begin{array}{\|l} \text { Reverse Voltage } \\ \text { 3C91C, 3C92C (TX) } \end{array}$ | 7 | - | - | V | $\mathrm{I}_{\mathrm{R}}=0.1 \mathrm{~mA}$ |
| $I_{\text {R }}$ | ```Reverse Current 3C91C, 3C92C (TX) 3N243, 3N244, 3N245 (TX) 3N262``` | - | - | $\begin{gathered} 1 \\ 100 \\ 100 \end{gathered}$ | $\mu \mathrm{A}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{R}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{R}}=2.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{R}}=2.0 \mathrm{~V} \end{aligned}$ |
| $\mathrm{Cl}_{\text {IN }}$ | Diode Capacitance 3C91C, 3C92C (TX) | - | 25 | - | pF | $V=0, f=1 \mathrm{MHz}$ |

Output Phototransistor

| $\mathrm{V}_{\text {(BR) }}$ CEO | ```Collector-Emitter Breakdown Voltage 3C91C, 3C92C (TX) 3N243, 3N244, 3N245 (TX) 3N262``` | $\begin{aligned} & 50 \\ & 30 \\ & 40 \end{aligned}$ | - |  | v | $\begin{aligned} & \mathrm{I}_{\mathrm{c}}=10.0 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{c}}=1.0 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{c}}=1.0 \mathrm{~mA} \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {(BR) }}$ Eco | ```Emitter-Collector Breakdown Voltage 3C91C, 3C92C (TX) 3N243, 3N244, 3N245 (TX) 3N262``` | $\begin{aligned} & 7 \\ & 5 \\ & 7 \end{aligned}$ | - |  | V | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=10 \mu \mathrm{~A} \\ & \mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A} \\ & \mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A} \end{aligned}$ |
| $\mathrm{I}_{\text {ceo }}$ | $\begin{array}{\|l} \text { Collector Dark Current } \\ \text { 3C91C, 3C92C (TX) } \\ \text { 3C91C, 3C92C (TX) } \\ \text { 3N243, 3N244, 3N245 (TX) } \\ \text { 3N243, 3N244, 3N245 (TX) } \\ \text { 3N262 } \\ \text { 3N262 } \end{array}$ |  | - - - - - | $\begin{gathered} 10 \\ 50 \\ 100 \\ 100 \\ 100 \\ 100 \end{gathered}$ | nA nA nA $\mu \mathrm{A}$ $\mu \mathrm{A}$ $\mu \mathrm{A}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CE}}=50 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=100^{\circ} \mathrm{C} \\ & \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=100^{\circ} \mathrm{C} \end{aligned}$ |

## Electrical Specifications

Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |

## Coupled

| $I_{\text {c(oon) }}$ | On-State Collector Current 3C91C, 3C92C (TX) 3C91C, 3C92C (TX) 3N243 3N243 3N243 3N243 3N244 3N244 3N244 3N244 3N245 (TX) 3N245 (TX) 3N245 (TX) 3N245 (TX) 3N262 3N262 3N262 | $\begin{aligned} & 4.0 \\ & 3.0 \\ & 1.5 \\ & 0.3 \\ & 0.5 \\ & 0.5 \\ & 3.0 \\ & 0.8 \\ & 1.0 \\ & 1.0 \\ & 6.0 \\ & 1.5 \\ & 1.5 \\ & 1.5 \\ & 1.0 \\ & 1.4 \\ & 1.0 \end{aligned}$ | - <br> - <br> - <br> - <br> - <br> - <br> - <br> - <br> - <br> - <br> - <br> - <br> - <br> - | $20$ | mA | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=0.4 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{F}}=3 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=55^{\circ} \mathrm{C} \\ & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=100^{\circ} \mathrm{C} \\ & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{F}}=3 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=55^{\circ} \mathrm{C} \\ & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=100^{\circ} \mathrm{C} \\ & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{F}}=3 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=55^{\circ} \mathrm{C} \\ & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=100^{\circ} \\ & \mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{F}}=2.0 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=55^{\circ} \mathrm{C} \\ & \mathrm{I}_{\mathrm{F}}=2.0 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=10{ }^{\circ} \mathrm{Cl} \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {CEISAT }}$ | ```Collector-Emitter Saturation Voltage 3C91C, 3C92C (TX) 3N243, 3N244, 3N245 (TX) 3N243, 3N244, 3N245 (TX) 3N243, 3N244, 3N245 (TX) 3N262 3N262 3N262``` |  | - <br> - <br> - <br> - <br>  | $\begin{aligned} & 0.4 \\ & 0.3 \\ & 0.3 \\ & 0.3 \\ & 0.3 \\ & 0.3 \\ & 0.3 \end{aligned}$ | V | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=50 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{F}} 20 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=1.50 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=3.0 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=6.0 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{F}}=2.0 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=0.50 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{F}}=2.0 \mathrm{~mA}, \mathrm{I}_{\mathrm{I}}=1.0 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{F}}=2.0 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=2.0 \mathrm{~mA} \end{aligned}$ |
| $\mathrm{t}_{\text {on }}$ | $\begin{aligned} & \text { Turn-on Time } \\ & \text { 3C91C, 3C92C (TX) } \end{aligned}$ | - | - | 9 | $\mu \mathrm{s}$ | $\mathrm{V}_{\mathrm{cC}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=2 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ |
| $\mathrm{t}_{\text {IOFF }}$ | $\begin{aligned} & \text { Turn-off Time } \\ & \text { 3C91C, 3C92C (TX) } \end{aligned}$ | - | - | 6 | $\mu \mathrm{s}$ | $\mathrm{V}_{\mathrm{cc}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=2 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ |

## Electrical Specifications

Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |

Coupled

| $C_{10}$ | $\begin{aligned} & \text { Input-to-Output Capacitance } \\ & \text { 3C91C, 3C92C (TX) } \\ & \text { 3N243, 3N244, 3N245 (TX) } \\ & \text { 3N262 } \end{aligned}$ | - | $2$ | $\begin{aligned} & 2.5 \\ & 5.0 \\ & 5.0 \end{aligned}$ | pF | $\begin{aligned} & \mathrm{f}=1 \mathrm{MHz} \\ & \mathrm{~V}_{10}=0 \mathrm{~V}, \mathrm{f}=1.00 \mathrm{MHz}^{(1)} \\ & \mathrm{V}_{10}=0 \mathrm{~V}, \mathrm{f}=1.00 \mathrm{MHz}^{(1)} \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 110 | Leakage Input -to-Output 3N243, 3N244, 3N245 (TX) 3N262 |  | - | $\begin{gathered} 100 \\ 10 \end{gathered}$ | nA | $\begin{aligned} & \mathrm{V}_{10}= \pm 1.00 \mathrm{kVDC}^{(1)} \\ & \mathrm{V}_{10}= \pm 1.00 \mathrm{kVDC}^{(1)} \end{aligned}$ |
| $\mathrm{R}_{10}$ | Isolation Resistance 3C91C, 3C92C (TX) | $10^{9}$ | - | - | $\Omega$ | $\mathrm{V}_{10}=+1 \mathrm{kV}$ |
| $\mathrm{t}_{\mathrm{r}}$ | Output Rise Time 3N243, 3N244, 3N245 (TX) 3N262 |  | - | $\begin{aligned} & 10 \\ & 20 \end{aligned}$ | $\mu \mathrm{s}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10.0 \mathrm{~V}, I_{\mathrm{F}}=10.0 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega^{(2)} \\ & \mathrm{V}_{\mathrm{CC}}=10.0 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=5.0 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega^{(2)} \end{aligned}$ |
| $\mathrm{t}_{\mathrm{f}}$ | Output Fall Time 3N243, 3N244, 3N245 (TX) 3N262 |  | - | $\begin{aligned} & 10 \\ & 10 \end{aligned}$ | $\mu \mathrm{s}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=10.0 \mathrm{~V}, I_{\mathrm{F}}=10.0 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega^{(2)} \\ & \mathrm{V}_{\mathrm{CC}}=10.0 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=5.0 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega^{(2)} \end{aligned}$ |

Notes:

1. Measured with input leads shorted together and output leads shorted together.
2. The input waveform is supplied by a generator with the following characteristics: $\mathrm{Z}_{\text {out }}=50 \Omega, \mathrm{t}_{\mathrm{r}} \leq 15 \mathrm{~ns}$, duty cycle $\sim 1 \%$, pulse width $\sim 100 \mathrm{~ms}$.


## X-ON Electronics

Largest Supplier of Electrical and Electronic Components
Click to view similar products for Transistor Output Optocouplers category:
Click to view products by TT Electronics manufacturer:
Other Similar products are found below :
LTV-814S-TA LTV-824HS 66095-001 6N136-X017T MCT6-X007 MOC8101-X017T PS2561A-1-W-A PS2561B-1-L-A PS2561L-1-V-A MRF658 IL755-1X007 ILD2-X006 ILD74-X001 ILQ615-2X017 ILQ615-3X016 LDA102S LDA110S PS2561-1-V-W-A PS2561AL-1-VA PS2561L1-1-L-A PS2701A-1-F3-P-A PS2801-1-F3-P-A PS2911-1-L-AX CNY17-2X017 CNY17-4X001 CNY17-4X017 CNY17F1 X007 CNY17F-2X017 CNY17F-4X001 CNY17G-1 LTV-214 LTV-702VB LTV-733S LTV-816S-TA LTV-825S TCET1113 TCET2100 4N25-X007T IL215AT ILD615-1X007 ILQ2-X007 VOS615A-2T WPPC-A11066AA WPPC-A11066AD WPPC-A11084ASS WPPCA21068AA WPPC-D11066AA WPPC-D21068ED WPPC-D410616EA WPPC-D410616ED

